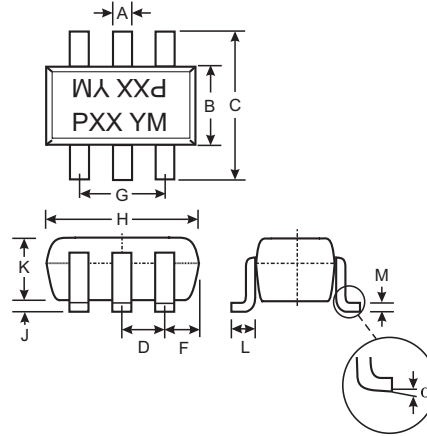


Features

- Epitaxial Planar Die Construction
- Built-In Biasing Resistors
- Lead Free/RoHS Compliant (Note 3)

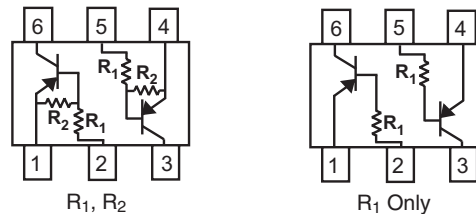
Mechanical Data

- Case: SOT-363
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking: Date Code and Marking Code (See Diagrams & Page 3)
- Ordering Information (See Page 3)
- Weight: 0.006 grams (approx.)



SOT-363		
Dim	Min	Max
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Nominal	
F	0.30	0.40
H	1.80	2.20
J	—	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.25
α	0°	8°
All Dimensions in mm		

P/N	R1	R2	MARKING
DDA124EU	22KΩ	22KΩ	P17
DDA144EU	47KΩ	47KΩ	P20
DDA114YU	10KΩ	47KΩ	P14
DDA123JU	2.2KΩ	47KΩ	P06
DDA114EU	10KΩ	10KΩ	P13
DDA113TU	1KΩ	—	P01
DDA143TU	4.7KΩ	—	P07
DDA114TU	10KΩ	—	P12



SCHEMATIC DIAGRAM

Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage, (1) to (6) and (4) to (3)	V _{CC}	50	V
Input Voltage, (1) to (2) and (4) to (5)	V _{IN}	DDA124EU DDA144EU DDA114YU DDA123JU DDA114EU DDA113TU DDA143TU DDA114TU +10 to -40 +10 to -40 +6 to -40 +5 to -12 +10 to -40 +5 V _{max} +5 V _{max} +5 V _{max}	V
Output Current	I _O	DDA124EU DDA144EU DDA114YU DDA123JU DDA114EU DDA113TU DDA143TU DDA114TU -30 -30 -70 -100 -50 -100 -100 -100	mA
Output Current	I _C (Max)	All	-100 mA
Power Dissipation (Total)	P _d	200	mW
Thermal Resistance, Junction to Ambient Air (Note 1)	R _{θJA}	625	°C/W

- Note: 1. Mounted on FR4 PC Board with recommended pad layout at <http://www.diodes.com/datasheets/ap02001.pdf>.
 2. 150mW per element must not be exceeded.
 3. No purposefully added lead.

Electrical Characteristics @ T_A = 25°C unless otherwise specified

Characteristic (DDA113TU & DDA143TU & DDA114TU only)	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-50	—	—	V	I _C = -50μA
Collector-Emitter Breakdown Voltage	BV _{CEO}	-50	—	—	V	I _C = -1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	—	—	V	I _E = -50μA
Collector Cutoff Current	I _{CBO}	—	—	-0.5	μA	V _{CB} = -50V
Emitter Cutoff Current	I _{EBO}	—	—	-0.5	μA	V _{EB} = -4V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	—	—	-0.3	V	I _C /I _B = -2.5mA / -0.25mA DDA143TU I _C /I _B = -1mA / -0.1mA DDA114TU I _C /I _B = -10mA / -1mA DDA113TU
DC Current Transfer Ratio	h _{FE}	100	250	600	—	I _C = -1mA, V _{CE} = -5V
Input Resistor (R ₁) Tolerance	ΔR ₁	-30	—	+30	%	—
Gain-Bandwidth Product*	f _T	—	250	—	MHz	V _{CE} = -10V, I _E = 5mA, f = 100MHz

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition	
Input Voltage	V _{I(off)}	DDA124EU	-0.5	-1.1	—	V	V _{CC} = -5V, I _O = -100μA
		DDA144EU	-0.5	-1.1			
Input Voltage	V _{I(on)}	DDA114YU	-0.3	—	—	V	V _O = -0.3, I _O = -5mA
		DDA123JU	-0.5	—			
Input Voltage	V _{I(on)}	DDA114EU	-0.5	-1.1	—	V	V _O = -0.3, I _O = -2mA
		DDA124EU	—	-1.9			
Input Voltage	V _{I(on)}	DDA144EU	—	-1.9	—	V	V _O = -0.3, I _O = -1mA
		DDA114YU	—	-1.4			
Input Voltage	V _{I(on)}	DDA123JU	—	-1.1	—	V	V _O = -0.3, I _O = -5mA
		DDA114EU	—	-1.9			
Output Voltage	V _{O(on)}	DDA124EU	—	-0.1	—	V	I _O /I _I = -10mA / -0.5mA
		DDA144EU	—	-0.1			
Output Voltage	V _{O(on)}	DDA114YU	—	-0.1	—	V	I _O /I _I = -10mA / -0.5mA
		DDA123JU	—	-0.1			
Output Voltage	V _{O(on)}	DDA123JU	—	-0.1	—	V	I _O /I _I = -5mA / -0.25mA
		DDA114EU	—	-0.1			
Input Current	I _I	DDA124EU	—	—	—	mA	V _I = -5V
		DDA144EU	—	—			
Input Current	I _I	DDA114YU	—	—	—	mA	V _I = -5V
		DDA123JU	—	—			
Input Current	I _I	DDA123JU	—	—	—	mA	V _I = -5V
		DDA114EU	—	—			
Output Current	I _{O(off)}	—	—	-0.5	μA	V _{CC} = -50V, V _I = -0V	
DC Current Gain	G _I	DDA124EU	56	—	—	—	V _O = -5V, I _O = -5mA
		DDA144EU	68	—	—	—	V _O = -5V, I _O = -5mA
DC Current Gain	G _I	DDA114YU	68	—	—	—	V _O = -5V, I _O = -10mA
		DDA123JU	80	—	—	—	V _O = -5V, I _O = -10mA
DC Current Gain	G _I	DDA123JU	80	—	—	—	V _O = -5V, I _O = -10mA
		DDA114EU	30	—	—	—	V _O = -5V, I _O = -5mA
Input Resistor (R ₁) Tolerance	ΔR ₁	-30	—	+30	%	—	
Resistance Ratio Tolerance	R ₂ /R ₁	-20	—	+20	%	—	
Gain-Bandwidth Product*	f _T	—	250	—	MHz	V _{CE} = -10V, I _E = -5mA, f = 100MHz	

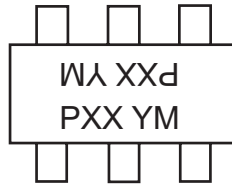
* Transistor - For Reference Only

Ordering Information (Note 4)

Device	Packaging	Shipping
DDA124EU-7-F	SOT-363	3000/Tape & Reel
DDA144EU-7-F	SOT-363	3000/Tape & Reel
DDA114YU-7-F	SOT-363	3000/Tape & Reel
DDA123JU-7-F	SOT-363	3000/Tape & Reel
DDA114EU-7-F	SOT-363	3000/Tape & Reel
DDA113TU-7-F	SOT-363	3000/Tape & Reel
DDA143TU-7-F	SOT-363	3000/Tape & Reel
DDA114TU-7-F	SOT-363	3000/Tape & Reel

Notes: 4. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



PXX = Product Type Marking Code
See Sheet 1 Diagrams
YM = Date Code Marking
Y = Year ex: T = 2006
M = Month ex: 9 = September

Date Code Key

Year	2004	2005	2006	2007	2008	2009	2010	2011
Code	R	S	T	U	V	W	X	Y

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

TYPICAL CURVES - DDA123JU
ONE SECTION

NEW PRODUCT

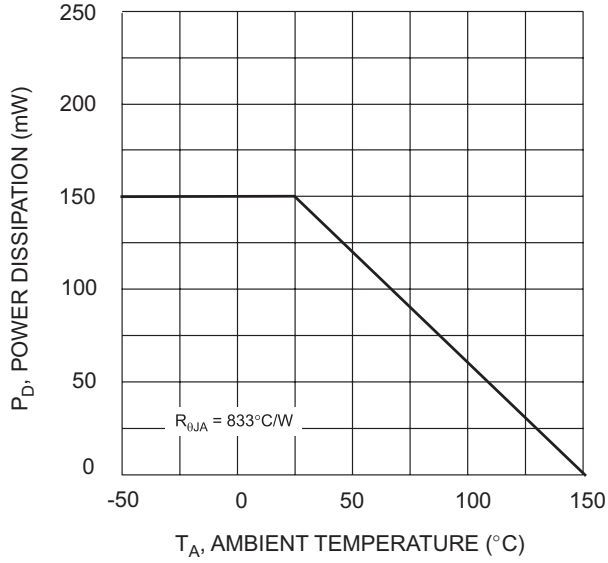


Fig. 1 Derating Curve

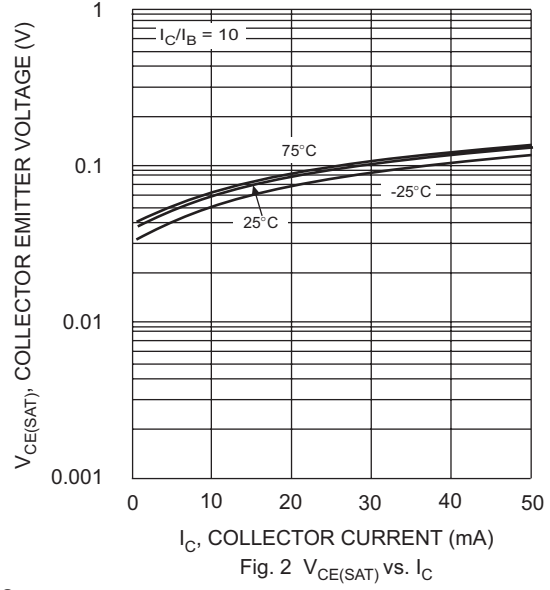


Fig. 2 $V_{CE(SAT)}$ vs. I_C

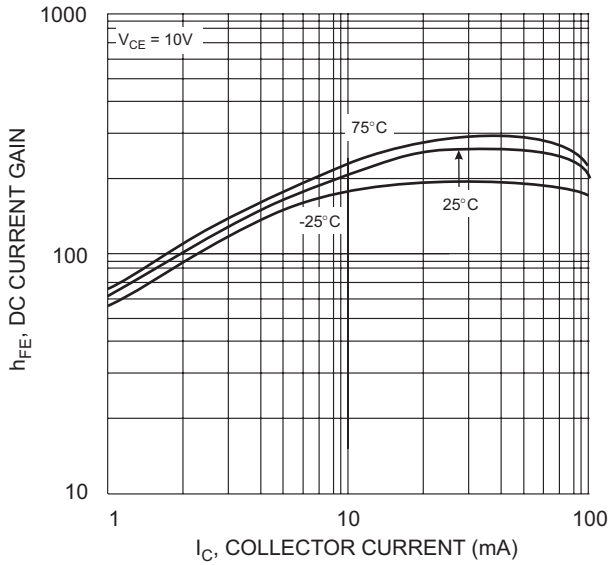


Fig. 3 DC Current Gain

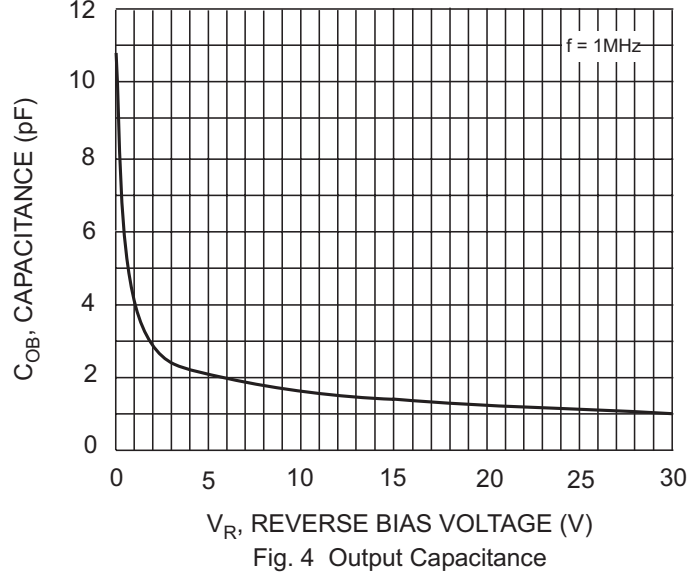


Fig. 4 Output Capacitance

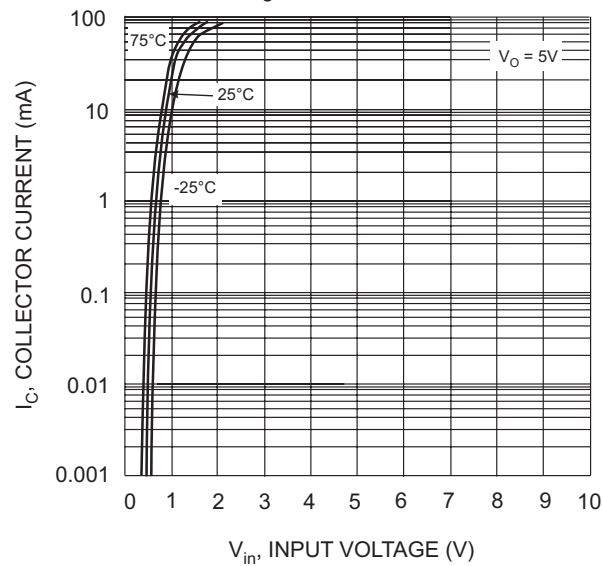


Fig. 5 Collector Current Vs. Input Voltage

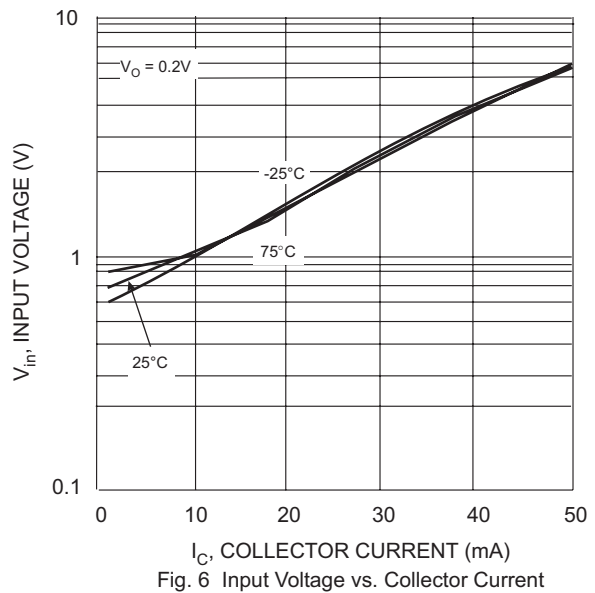


Fig. 6 Input Voltage vs. Collector Current

TYPICAL CURVES - DDA114TU
ONE SECTION

NEW PRODUCT

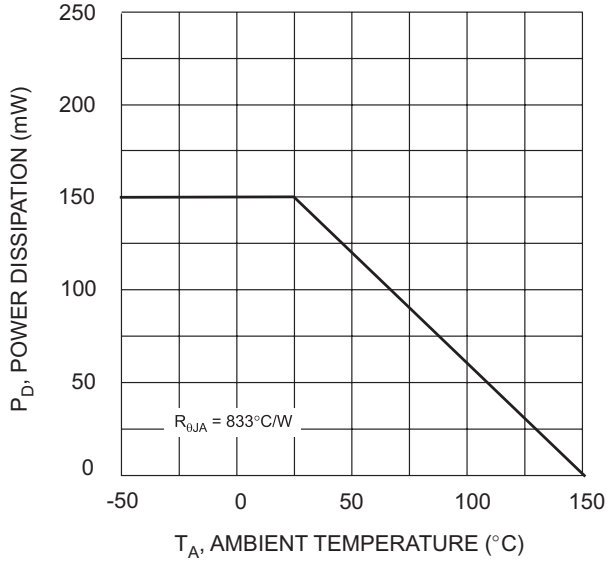


Fig. 1 Derating Curve

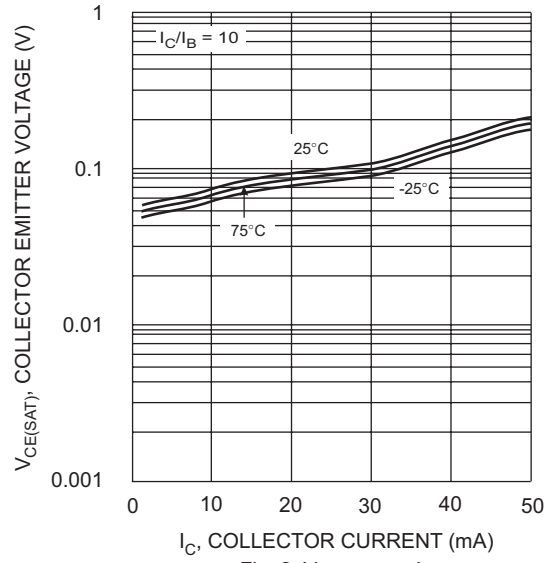


Fig. 2 $V_{CE(SAT)}$ vs. I_C

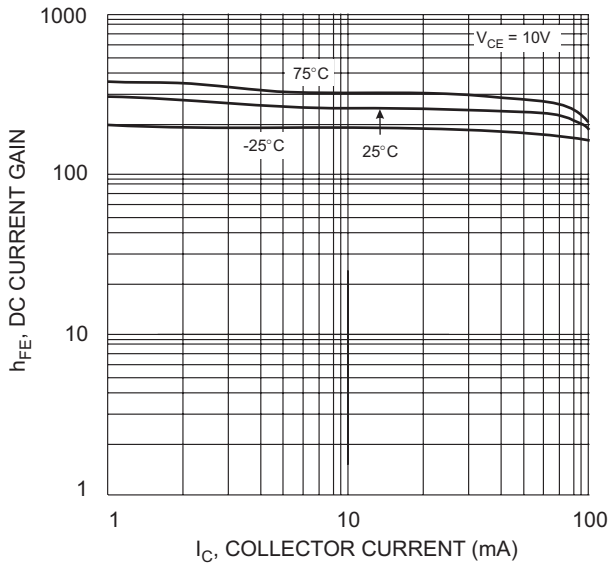


Fig. 3 DC Current Gain

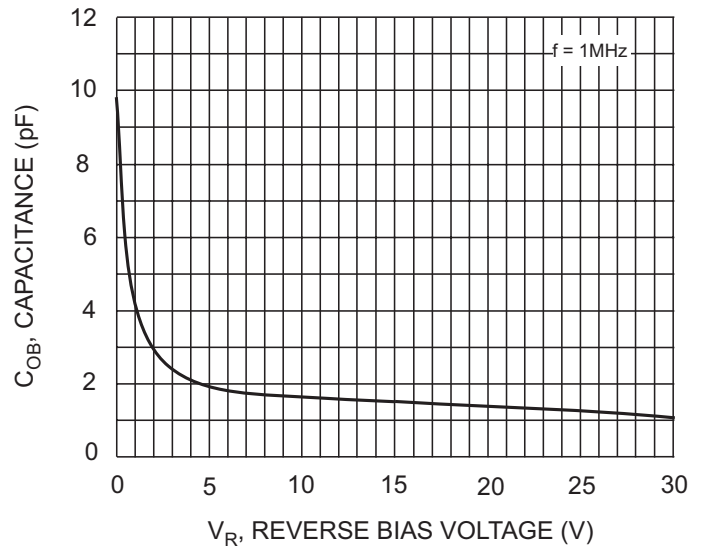


Fig. 4 Output Capacitance

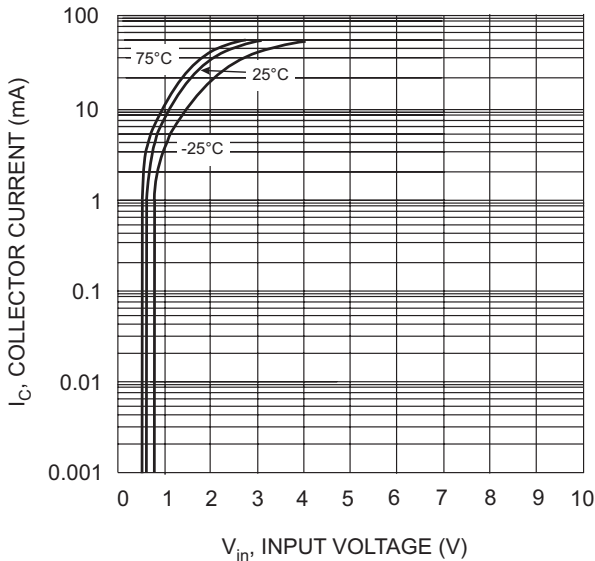


Fig. 5 Collector Current Vs. Input Voltage

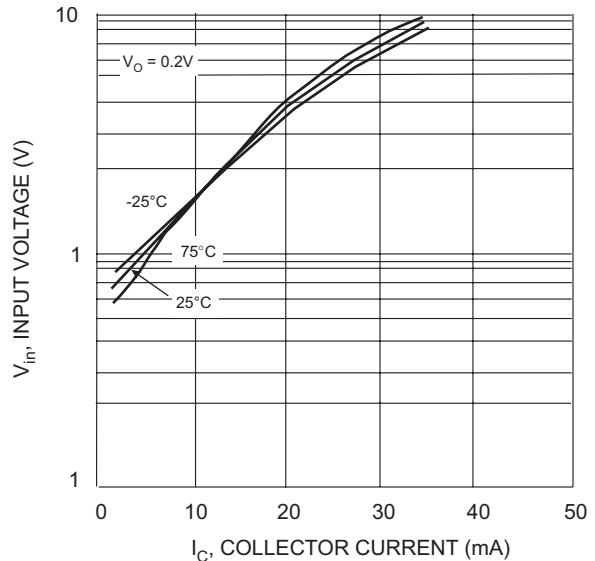


Fig. 6 Input Voltage vs. Collector Current

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